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AIRCHIL

SEMICONDUCTO

Dual P-Channel 2.5V Specified PowerTrench^o MOSFET

General Description

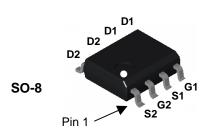
This P-Channel MOSFET is a rugged gate version of Fairchild Semiconductor's advanced PowerTrench process. It has been optimized for power management applications with a wide range of gate drive voltage (2.5V - 12V).

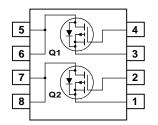
Applications

- Load switch
- Motor drive
- DC/DC conversion
- Power management

Features

- -5 A, -20 V, $R_{DS(ON)} = 55 \text{ m}\Omega @ V_{GS} = -4.5 \text{ V}$ $R_{DS(ON)} = 90 \text{ m}\Omega @ V_{GS} = -2.5 \text{ V}$
- Extended V_{GSS} range (±12V) for battery applications
- Low gate charge
- High performance trench technology for extremely low $R_{\text{DS}(\text{ON})}$
- High power and current handling capability



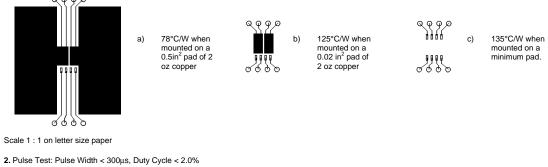


Absolute Maximum Ratings T_A=25°C unless otherwise noted

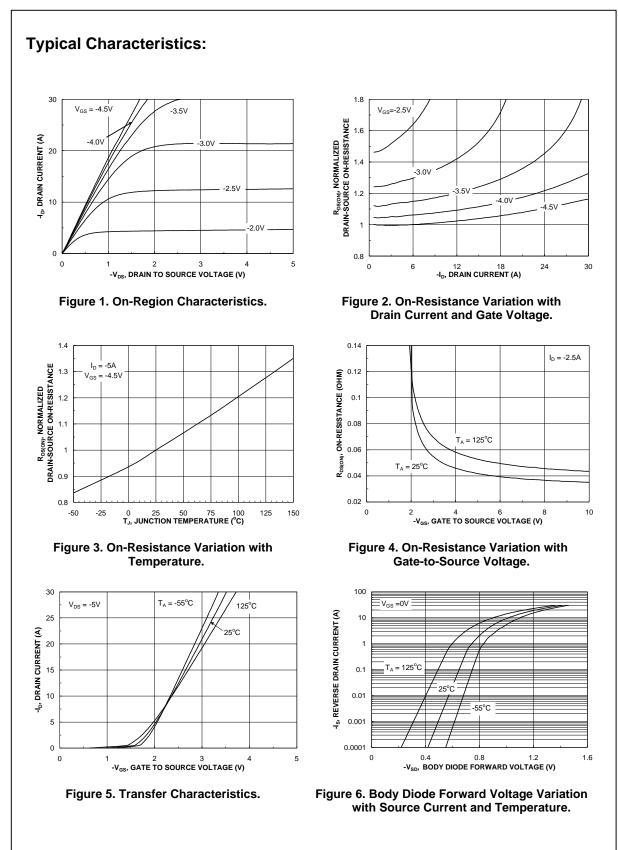
Symbol		Parameter		Ratings	Units
V _{DSS}	Drain-Sourc	e Voltage		-20	V
V _{GSS}	Gate-Source	e Voltage		±12	V
ID	Drain Currer	nt – Continuous	(Note 1a)	-5	A
		– Pulsed		-30	
PD	Power Dissipation for Dual Operation			2	W
	Power Dissi	pation for Single Operation	(Note 1a)	1.6	
			(Note 1b)	1	
			(Note 1c)	0.9	
T _J , T _{STG}	Operating an	nd Storage Junction Temp	erature Range	-55 to +175	°C
Therma	I Charact	eristics			
R _{0JA}	Thermal Res	sistance, Junction-to-Ambi	ent (Note 1a)	78	°C/W
R _{θJC}	Thermal Res	al Resistance, Junction-to-Case (Note 1)		40 °(
Packag	e Marking	g and Ordering Ir	nformation		
-	Marking	Device	Reel Size	Tape width	Quantity
99	33	FDS9933	13"	12mm	2500 units

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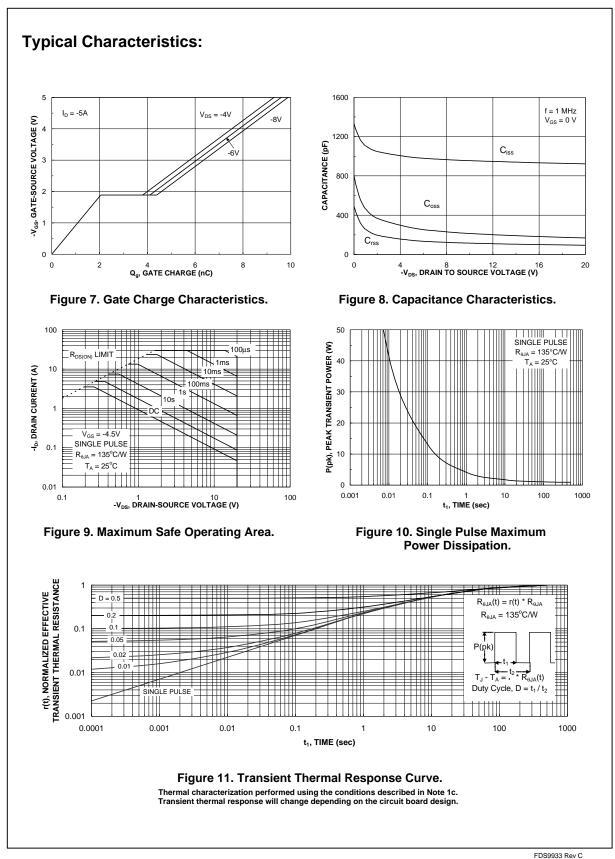
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Char	acteristics				•	•
BV _{DSS}	Drain–Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_D = -250 \mu\text{A}$	-20			V
<u>ΔBV_{DSS}</u> ΔT _J	Breakdown Voltage Temperature Coefficient	$I_D = -250 \ \mu\text{A}$, Referenced to 25°C		-12		mV/°C
DSS	Zero Gate Voltage Drain Current	$V_{DS} = -16 \text{ V}, V_{GS} = 0 \text{ V}$			-1	μΑ
GSS	Gate-Body Leakage	$V_{GS} = \pm 12 \text{ V}, V_{DS} = 0 \text{ V}$			±100	nA
On Char	acteristics (Note 2)		•		•	•
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = -250 \ \mu A$	-0.6	-0.8	-1.2	V
$\Delta V_{GS(th)}$ ΔT_J	Gate Threshold Voltage Temperature Coefficient	$I_D = -250 \ \mu\text{A}$, Referenced to 25°C		3		mV/°C
R _{DS(on)}	Static Drain–Source	$V_{GS} = -4.5 \text{ V}, I_D = -3.2 \text{ A}$		44	55	mΩ
	On–Resistance	$ \begin{array}{ll} V_{GS} = -2.5 \ V, & I_D = -1.0 \ A \\ V_{GS} = -4.5 \ V, & V_{DS} = -5 \ V \end{array} $	40	72	90	•
D(on)	On–State Drain Current		-16			A
g fs	Forward Transconductance	$V_{DS} = -9 V$, $I_D = -3.4 A$		8		S
Dynamic	Characteristics			-	-	-
C _{iss}	Input Capacitance	$V_{DS} = -10 V$, $V_{GS} = 0 V$,		825		pF
C _{oss}	Output Capacitance	f = 1.0 MHz		420		pF
C _{rss}	Reverse Transfer Capacitance			150		pF
Switchin	ng Characteristics (Note 2)					
d(on)	Turn–On Delay Time	$V_{DD} = -10 \text{ V}, \qquad I_D = -1 \text{ A},$		16	40	ns
tr	Turn–On Rise Time	$V_{GS} = -4.5 \text{ V}, \qquad R_{GEN} = 6 \Omega$		46	80	ns
d(off)	Turn–Off Delay Time			40	70	ns
lf .	Turn–Off Fall Time			25	40	ns
Qg	Total Gate Charge	$V_{DS} = -6 V$, $I_D = -3.2A$,		10	20	nC
Q _{gs}	Gate-Source Charge	$V_{GS} = -4.5 V$		2.1		nC
Q _{gd}	Gate-Drain Charge			3.3		nC
Drain-S	ource Diode Characteristics	and Maximum Ratings				
s	Maximum Continuous Drain-Source				-2.0	Α
V _{SD}	Drain–Source Diode Forward Voltage	$V_{GS} = 0 V$, $I_S = -2.0 A$ (Note 2)		-0.7	-1.2	V



FDS9933 Rev C



FDS9933 Rev C



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